

#### **Features:**

- 1200V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

#### **Benefits:**

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

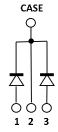
Symbol	Value	Unit	
$V_{RRM}$	1200	V	
$I_F \; (_{Tc=153} \text{°C})$	30	A	
* <b>Q</b> C	113	пC	

## **Applications:**

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

# Outline





Circuit

**TO-247-3** 

#### **Maximum Ratings (\*Per leg)**

Symbol	Parameter	Value	Unit	Test Conditions
$V_R$	DC Peak Reverse Voltage	1200	V	$T_J = 25^{\circ}C$
V <sub>RRM</sub>	Repetitive Peak Reverse	1200	V	$T_J = 25^{\circ}C$
V <sub>RSM</sub>	Surge Peak Reverse Voltage	1300	V	$T_J = 25^{\circ}C$
$I_{\mathrm{F}}$	Continuous Forward Current	*48/96 *22.6/45.2 *15/30	A	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 135^{\circ}{\rm C}$ $T_{\rm C} = 153^{\circ}{\rm C}$
I <sub>FRM</sub>	Repetitive Peak Forward Surge Current	*129 *103	A	$T_C = 25^{\circ}\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave $T_C = 125^{\circ}\text{C}$ , $T_P = 10\text{ms}$ , Half Sine Wave
I <sub>FSM</sub>	Non-Repetitive Peak Forward Surge Current	*152 *137	A	$T_{C}=25^{\circ}\text{C}, T_{P}=10\text{ms}, \text{Half Sine Wave}$ $T_{C}=125^{\circ}\text{C}, T_{P}=10\text{ms}, \text{Half Sine Wave}$
P <sub>D</sub>	Power Dissipation	*214 *71	W	$T_C = 25^{\circ}C$ $T_C = 125^{\circ}C$
T <sub>J,max</sub>	Operating Junction Temperature	175	°C	
T <sub>stg</sub>	Storage Temperature Range	-55 to 175	$^{\circ}\mathrm{C}$	



#### Thermal characteristics (\*Per Leg)

Symbol	Parameter	Min.	Тур.	Max.	Unit
$\mathbf{R}_{ ext{thJC}}$	Thermal resistance		*0.70/0.35		°C/W

#### **Electrical Characteristics (Per leg)**

Carrelle 1	Parameter	Value		T I 24	T. A.C. Per	
Symbol		Min.	Тур.	Max.	Unit	Test Conditions
V <sub>DC</sub>	DC Blocking Voltage	1200			V	$I_R = 200 \mu A, T_J = 25^{\circ} C$
$\mathbf{V_F}$	Forward Voltage		1.5	1.8	V	$I_F = 15A, T_J = 25^{\circ}C$
V F	roiward voitage		2.0	2.4	V	$I_F = 15A, T_J = 175^{\circ}C$
Τ_	Reverse Current		5	100	μА	$V_R = 1200V, T_J = 25^{\circ}C$
$I_R$	Reverse Current		10	200		$V_R = 1200V, T_J = 175^{\circ}C$
0	Total Compositive Change		113		nC	$I_F = 15A$ , $dI/dt = 400A/\mu s$
$\mathbf{Q}_{\mathrm{C}}$	Total Capacitive Charge		113		nC	$T_J = 25^{\circ}C, V_R = 800V$
			715			$V_R = 1V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$
C	Total Capacitance		98	98 p		$V_R = 400V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$
			82			$V_R = 800V, T_J = 25^{\circ}C, f = 1 \text{ MHz}$

#### **Typical Performance (Per Leg)**

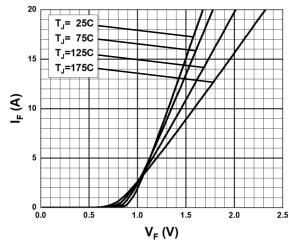


Fig. 1 Forward Characteristics

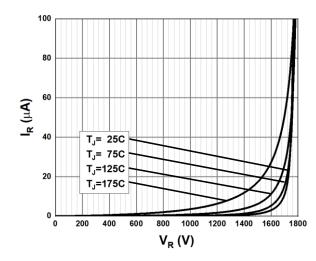
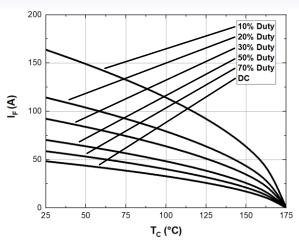


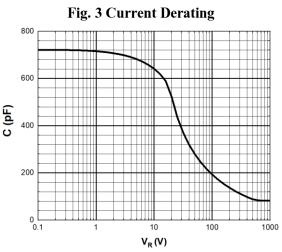
Fig. 2 Reverse Characteristics



#### **Typical Performance (Per Leg)**



250 200 150 50 0 25 50 75 100 125 150 175 T<sub>c</sub> (°C)



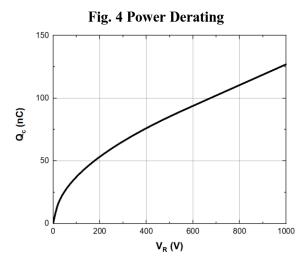
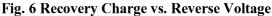
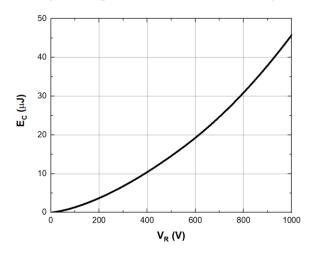


Fig. 5 Capacitance vs. Reverse Voltage





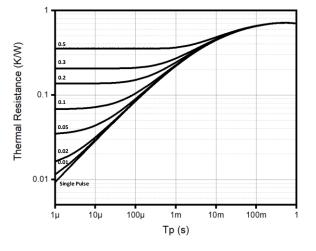


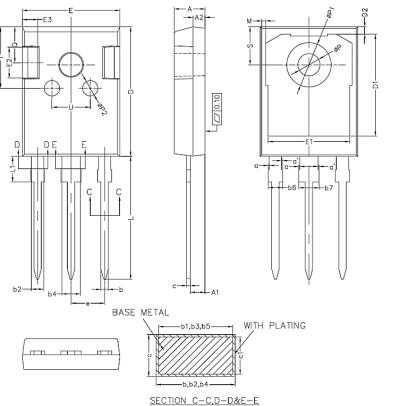
Fig. 7 Capacitance stored Energy

Fig. 8 Transient Thermal Impedance

S4D120V030D, Rev. 1.1 Page 3 of 4



## Package TO-247-3 (Unit: mm)



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX		
Α	4.90	5.00	5.10		
A1	2.31	2.41	2.51		
A2	1.90	2.00	2.10		
a	0	_	0.15		
a'	0	_	0.15		
b	1.16	_	1.26		
b1	1.15	1.2	1.22		
b2	1.96	_	2.06		
b3	1.95	2.00	2.02		
b4	2.96	-	3.06		
b5	2.95	3.00	3.02		
b6	_	1	2.25		
b7	_	_	3.25		
С	0.59	_	0.66		
c1	0.58	0.60	0.62		
D	20.90	21.00	21.10		
D1	16.25	16.55	16.85		
D2	1.05	1.20	1.35		
E	15.70	15.80	15.90		
E1	13.10	13.30	13.50		
E2	4.90	5.00	5.10		
E3	2.40	2.50	2.60		
е	5.34	5.44	5.54		
L	19.80	19.92	20.10		
L1	_	_	4.30		
М	0.35	_	0.95		
P	3.50	3.60	3.70		
P1	7.00	_	7.40		
P2	2.40	2.50	2.60		
Q	5.60	_	6.00		
S	6.05	6.15	6.25		
T	9.80	-	10.20		
U	6.00	_	6.40		
NS REFER TO JEDEC STANDARD					

NOTES: U 6.00 
1.ALL DIMENSIONS REFER TO JEDEC STANDAF
TO -247 AD DO NOT INCLUDE MOLD FLASH
OR PROTRUSIONS.
2.EJECTION MARK DEPTH 0.10±0.55.

This Product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, systems, or air-traffic control systems.

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, AZ Power Inc. disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.



5601 W SLAUSON AVE 190 CULVER CITY, CA 90230 WWW.AZPE.COM

Information in this document may change without notice. All referenced product or service names and trademarks are the property of their respective owners. Copyright © 2021 AZ Power Inc. All rights reserved.

S4D120V030D, Rev. 1.1